# **CNZ1413A** (ON1413A)

## **Integrated Photosensors**

#### ■ Overview

CNZ1413A are ultraminiature, highly reliable transmissive photosensors consisting of a high-efficiency GaAs infrared light emitting diode chip that is integrated with a high-sensitivity Siintegrated-photodetector chip in a double molded resin package.

#### ■ Features

• Ultraminiature: 4.2 mm × 4.2 mm (height: 5.2 mm)

• Fast response:  $t_{PHL} = 2.5 \mu s$ ,  $t_{PLH} = 6 \mu s$  (typ.)

• Highly precise position detection (slit width: 0.3 mm)

• Gap width: 1.2 mm

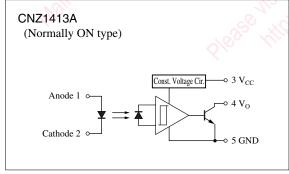
• With attachment positioning pin

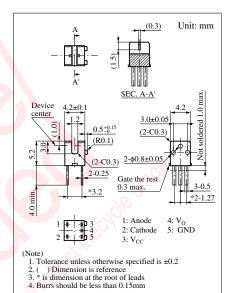
## ■ Absolute Maximum Ratings $T_a = 25$ °C

	Parameter	Symbol	Rating	Unit
Input (Light	Reverse voltage (DC)	$V_R$	6	V
emitting diode)	Forward current (DC)	$I_{F}$	50	mA
	Power dissipation *1	$P_{D}$	75	mW
Output	Output current	$I_{O}$	20	mA
(Photo IC)	Output voltage	Vo	30	v
	Supply voltage	V <sub>CC</sub>	17	V
	Power dissipation *2	P <sub>C</sub>	200	mW
Temperature	Operating ambient temperature	Topr	-25 to +85	°C
	Storage temperature	$T_{stg}$	-40 to +100	°C

Note) \*1: Input power derating ratio is 1.0 mW/°C at Ta = 25°C

### ■ Pin Connection





Note) The part number in the parenthesis shows conventional part number.

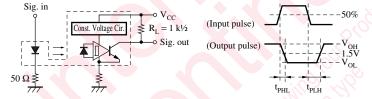
<sup>\*2:</sup> Output power derating ratio is 2.67 mW/°C at Ta = 25°C

## ■ Electro-optical Characteristics $T_a = 25$ °C

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input	Forward voltage (DC) V <sub>F</sub>		$I_F = 20 \text{ mA}$		1.2	1.4	V
characteristics	Reverse current (DC)	I <sub>R</sub>	$V_R = 3 V$			10	μΑ
Output	High output current	$I_{OH}$	$V_{CC} = 5 \text{ V}, V_{OH} = 30 \text{ V}, I_F = 0 \text{ mA}$			100	μΑ
characteristics	Low output voltage	V <sub>OL</sub>	$V_{CC} = 5 \text{ V}, I_{OL} = 20 \text{ mA}, I_{F} = 5 \text{ mA}$		0.15	0.4	V
	Operating power voltage	V <sub>CC</sub>			4.5	17	V
	Low-level supply current	I <sub>CCL</sub>	$V_{CC} = 5 \text{ V}, I_F = 5 \text{ mA}$		2.4	5	mA
	High-level supply current	I <sub>CCH</sub>	$V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}$		0.8	3	mA
Transfer	Threshold input current	$I_{FH \to L} (I_{FL \to H})$	$V_{CC} = 5 \text{ V}$			5	mA
characteristics	Hysteresis $I_{FLH}/I_{FHL}(I_{FHL}/I_{FHL})$		$V_{CC} = 5 \text{ V}$		0.7	701.	
	Response time	t <sub>PHL</sub> (t <sub>PLH</sub> ) *	$V_{CC} = 5 \text{ V}, I_F = 5 \text{ mA}, I_L = 1 \text{ K} \frac{1}{2}$		2.5(3.5)	180	μs
		t <sub>PLH</sub> (t <sub>PHL</sub> )*	$V_{CC} = 5 \text{ V}, I_F = 5 \text{ mA}, I_L = 1 \text{ K} \frac{1}{2}$		6(5)		μs

Note) 1. Normally On type characteristics is shown, ( ) shows Normally Off type

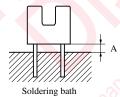
2. \*: Switching time measurement circuit



 $t_{PHL}: H \rightarrow L$  Propagation time  $t_{PLH}: L \rightarrow H$  Propagation time

## • Important Information for Soldering

### 1. Soldering Position



A: Make sure the distance is 0.1 mm or more.

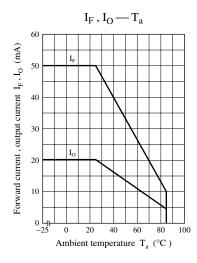
#### 2. Solder Temperature and Soldering Time

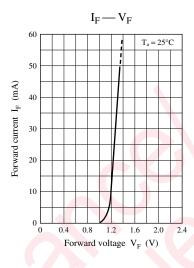
Temperature: 260°C or less Time: within 3 seconds

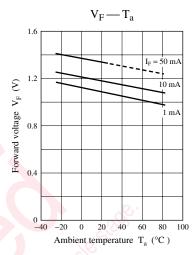
Note) Avoid using reflow soldering methods.

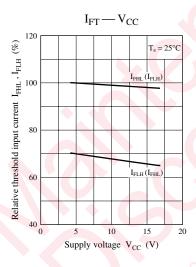
#### 3. Other Issues

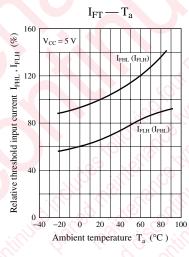
- 1) Soldering should not create excessive thermal or mechanical stress on the case package or leads. Excessive stress may cause changes in the shape or characteristics of the package or leads.
- Be careful not to allow solder, flux, solvents, etc. to remain on the case package.
   Doing so may cause problems related to transmission characteristics, etc.

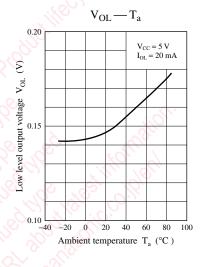


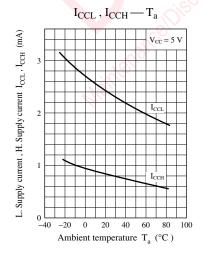


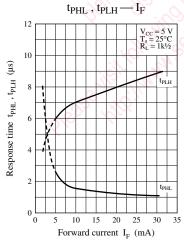


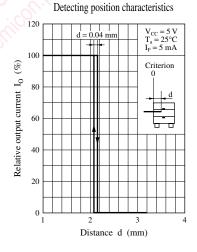












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## ■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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